

DSA 20 C 100 PN

 $I_{FAV} = 2x \cdot 10 A$

100 V

0.72 V

advanced

Schottky Diode

High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

Part number

• Very low Vf

• low Irm values

DSA 20 C 100 PN

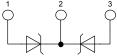
Features / Advantages:

• Extremely low switching losses

• High reliability circuit operation

• Low voltage peaks for reduced

• Improved thermal behaviour



FL E72873

Backside: isolated

- Industry standard outline
- RoHS compliant

Package:

 $V_{RRM} =$

- Housing: TO-220FP
- Plastic overmolded tab for electrical isolation
- Epoxy meets UL 94V-0

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

protection circuits Low noise switching

Ratings

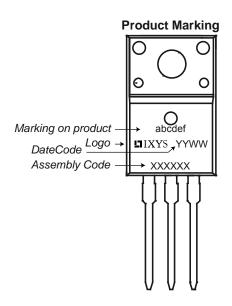
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RRM}	max. repetitive reverse voltage		T _{vJ} = 25°C			100	V
I _R	reverse current	V _R = 100 V	$T_{VJ} = 25^{\circ}C$			0.2	μA
		V _R = 100 V	$T_{VJ} = 125$ °C			2	mA
V _F	forward voltage	I _F = 10 A	$T_{VJ} = 25^{\circ}C$			0.90	V
		$I_F = 20 A$				1.50	V
		I _F = 10A	T _{VJ} = 125°C			0.72	V
		$I_F = 20 A$				0.88	V
I _{FAV}	average forward current	rectangular, d = 0.5	$T_{\rm C}$ = 145°C			10	Α
V _{F0}	threshold voltage		T _{vJ} = 175°C			0.46	V
r _F	slope resistance for power loss calculation only					17	mΩ
R_{thJC}	thermal resistance junction to case					4.50	K/W
T _{VJ}	virtual junction temperature			-55		175	°C
P _{tot}	total power dissipation		$T_{c} = 25^{\circ}C$			35	W
I _{FSM}	max. forward surge current	t = 10 ms (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			220	Α
CJ	junction capacitance	$V_R = \text{tbd V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		tbd		pF

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Ratings

Symbol	Definition	Conditions	min.	typ.	max.	Unit
I _{RMS}	RMS current	per pin 1)			35	Α
R _{thCH}	thermal resistance case to heats	ink		0.50		K/W
T _{stg}	storage temperature		-55		150	°C
Weight				2		g
M _D	mounting torque		0.4		0.8	Nm
F _c	mounting force with clip		20		60	N

¹⁾ I_{RMS} is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip. In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.



Part number

D = Diode

S = Schottky Diode

A = low VF

20 = Current Rating [A]

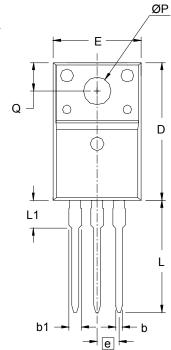
C = Common Cathode 100 = Reverse Voltage [V] PN = TO-220ACFP (3)

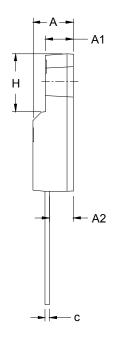
Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DSA 20 C 100 PN	DSA20C100PN	Tube	50	503516

Similar Part	Package	Voltage class
DSA20C100PB	TO-220	100
DSA20C60PN	TO-220FP	60
DSSK20-0045AM	TO-220	45
DSSK20-015A	TO-220	150

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Outlines





SYM	INCH	ÆS.	MILLIMETERS	
2114	MIN	MAX	MIN	MAX
Α	.177	.193	4.50	4.90
A1	.092	.108	2.34	2.74
A2	.101	.117	2.56	2.96
Ь	.028	.035	0.70	0.90
b1	.050	.058	1.27	1.47
С	.018	.024	0.45	0.60
D	.617	.633	15.67	16.07
E	.392	.408	9.96	10.36
е	.100 BSC		2.54 BSC	
Н	.255	.271	6.48	6.88
L	.499	.523	12.68	13.28
L1	.119	.135	3.03	3.43
ØΡ	.121	.129	3.08	3.28
Q	.126	.134	3.20	3.40